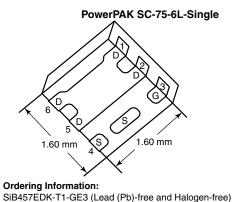


HALOGEN

FREE

# P-Channel 20 V (D-S) MOSFET

PRODUCT SUMMARY								
V <sub>DS</sub> (V)	$R_{DS(on)}(\Omega)$	I <sub>D</sub> (A)	Q <sub>g</sub> (Typ.)					
- 20	$0.035$ at $V_{GS} = -4.5 \text{ V}$	- 9 <sup>a</sup>						
	0.049 at V <sub>GS</sub> = - 2.5 V	- 9 <sup>a</sup>	13 nC					
	0.079 at V <sub>GS</sub> = - 1.8 V	- 9 <sup>a</sup>	13110					
	0.157 at V <sub>GS</sub> = - 1.5 V	- 2						



#### **FEATURES**

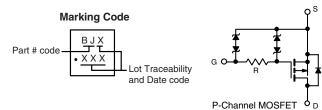
Halogen-free According to IEC 61249-2-21 Definition



- New Thermally Enhanced PowerPAK® SC-75 Package
  - Small Footprint Area
  - Low On-Resistance
- 100 % R<sub>g</sub> Tested
- Typical ESD Performance: 2500 V
- Built in ESD Protection with Zener Diode
- Compliant to RoHS Directive 2011/65/EU

### **APPLICATIONS**

- Load Switch for Portable Devices
- Load Switch for Charging Circuits



<b>ABSOLUTE MAXIMUM RATINGS</b>	(T <sub>A</sub> = 25 °C, unle	ess otherwise n	oted)			
Parameter		Symbol	Limit	Unit		
Drain-Source Voltage		V <sub>DS</sub>	- 20	V		
Gate-Source Voltage		$V_{GS}$	± 8	v		
	T <sub>C</sub> = 25 °C		- 9 <sup>a</sup>			
Continuous Drain Current (T <sub>.1</sub> = 150 °C)	T <sub>C</sub> = 70 °C		- 9 <sup>a</sup>			
Continuous Diain Current (1) = 150 C)	T <sub>A</sub> = 25 °C	I <sub>D</sub>	- 6.8 <sup>b, c</sup>			
	T <sub>A</sub> = 70 °C		- 5.5 <sup>b, c</sup>	Α		
Pulsed Drain Current		I <sub>DM</sub>	- 25			
Continuous Source-Drain Diode Current	T <sub>C</sub> = 25 °C	I.	- 9 <sup>a</sup>			
Continuous Godice-Diain Diode Guitent	T <sub>A</sub> = 25 °C	l <sub>S</sub>	- 2 <sup>b, c</sup>			
	T <sub>C</sub> = 25 °C		13			
Maximum Power Dissipation	T <sub>C</sub> = 70 °C	P <sub>D</sub>	8.4	w		
Maximum Fower Dissipation	T <sub>A</sub> = 25 °C	LD.	2.4 <sup>b, c</sup>	vv		
	T <sub>A</sub> = 70 °C		1.6 <sup>b, c</sup>			
Operating Junction and Storage Temperature Ra	ange	T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150	°C		
Soldering Recommendations (Peak Temperature		260				

THERMAL RESISTANCE RATINGS									
Parameter	Symbol	Typical	Maximum	Unit					
Maximum Junction-to-Ambient <sup>b, f</sup>	t ≤ 5 s	$R_{thJA}$	41	51	°C/W				
Maximum Junction-to-Case (Drain)	Steady State	R <sub>thJC</sub>	7.5	9.5	]				

#### Notes:

- a. Package limited.
- b. Surface mounted on 1" x 1" FR4 board.
- c. t = 5 s.
- d. See solder profile (www.vishay.com/doc?73257). The PowerPAK SC-75 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.
- f. Maximum under steady state conditions is 105 °C/W.

Document Number: 64816 S12-0497-Rev. C, 05-Mar-12 For more information please contact: pmostechsupport@vishay.com



Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit			
Static					L	L			
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	- 20			V			
V <sub>DS</sub> Temperature Coefficient	$\Delta V_{DS}/T_{J}$	L = 250 uA		- 12		mV/°C			
V <sub>GS(th)</sub> Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	I <sub>D</sub> = - 250 μA		2.5					
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 0.4		- 1	V			
Coto Source Lackage	lasa	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			± 5	μΑ			
Gate-Source Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$			± 0.5				
Zoro Coto Voltago Droin Current	1	V <sub>DS</sub> = - 20 V, V <sub>GS</sub> = 0 V							
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			- 10				
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \le -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	- 15			Α			
		V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 4.8 A		0.029 0.035					
		V <sub>GS</sub> = - 2.5 V, I <sub>D</sub> = - 4 A		0.040	0.049				
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = - 1.8 V, I <sub>D</sub> = - 3.3 A		0.060	0.079	Ω			
		V <sub>GS</sub> = - 1.5 V, I <sub>D</sub> = - 1.5 A		0.085	0.157	1			
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 10 V, I <sub>D</sub> = - 4.8 A		16		S			
Dynamic <sup>b</sup>									
Total Gate Charge	Q <sub>q</sub>	$V_{DS} = -10 \text{ V}, V_{GS} = -8 \text{ V}, I_{D} = -6.8 \text{ A}$		22	44				
Gate-Source Charge	<b>G</b> g			13	26	nC			
Gate-Source Charge	$Q_{gs}$	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -6.8 \text{ A}$		1.2					
Gate-Drain Charge	$Q_{gd}$			3					
Gate Resistance	$R_g$	f = 1 MHz	0.28	1.4	2.8	kΩ			
Turn-On Delay Time	t <sub>d(on)</sub>			0.34	0.51				
Rise Time	t <sub>r</sub>	$V_{DD} = -10 \text{ V}, R_{L} = 1.8 \Omega$		0.90	1.35				
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D \cong$ - 5.5 A, $V_{GEN}$ = - 4.5 V, $R_g$ = 1 $\Omega$		3	4.5				
Fall Time	t <sub>f</sub>			1.90	2.90	116			
Turn-On Delay Time	t <sub>d(on)</sub>			0.17	0.26	μs			
Rise Time	t <sub>r</sub>	$V_{DD}$ = - 10 V, $R_L$ = 1.8 $\Omega$		0.45	0.70	-			
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D \cong$ - 5.5 A, $V_{GEN}$ = - 8 V, $R_g$ = 1 $\Omega$		5.5	8.30				
Fall Time	t <sub>f</sub>			2	3.5				
Drain-Source Body Diode Characteristi	cs								
Continuous Source-Drain Diode Current	I <sub>S</sub>	T <sub>C</sub> = 25 °C			- 9	Α			
Pulse Diode Forward Current	I <sub>SM</sub>				- 25				
Body Diode Voltage	$V_{SD}$	I <sub>S</sub> = - 5.5 A, V <sub>GS</sub> = 0 V		- 0.85	- 1.2	V			

#### Notes:

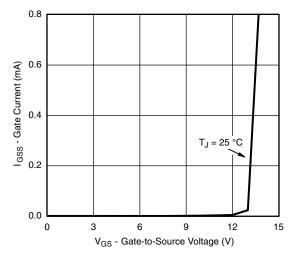
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

a. Pulse test; pulse width  $\leq 300~\mu s,$  duty cycle  $\leq 2~\%.$ 

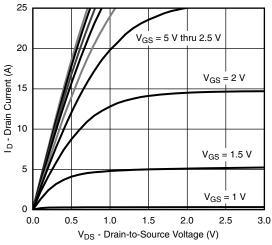
b. Guaranteed by design, not subject to production testing.



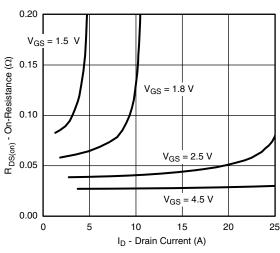
## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



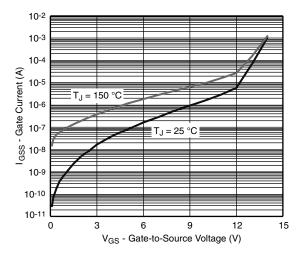
#### Gate Current vs. Gate-Source Voltage



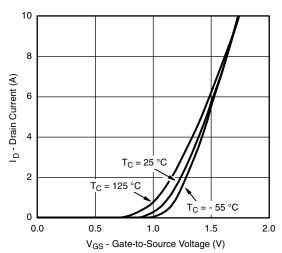
**Output Characteristics** 



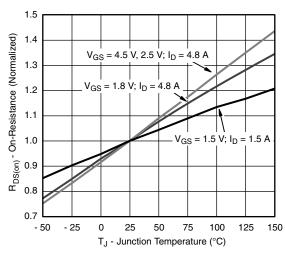
On-Resistance vs. Drain Current



**Gate Current vs. Gate-Source Voltage** 

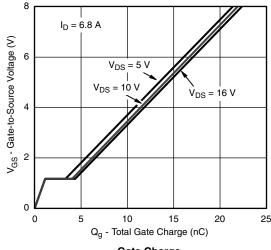


**Transfer Characteristics** 

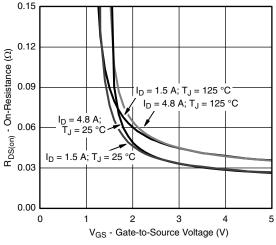


On-Resistance vs. Junction Temperature

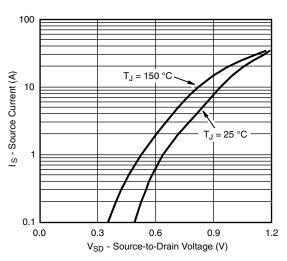
## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



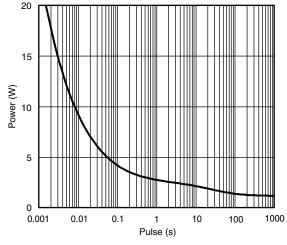




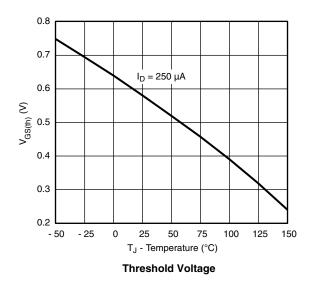
On-Resistance vs. Gate-to-Source Voltage

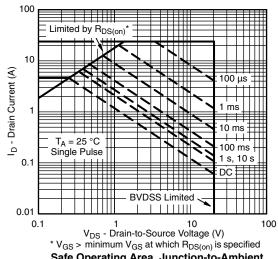


Soure-Drain Diode Forward Voltage



Single Pulse Power, Junction-to-Ambient





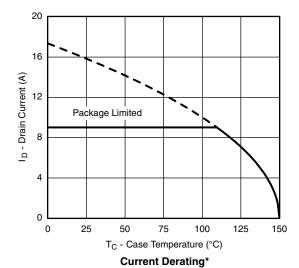
Safe Operating Area, Junction-to-Ambient

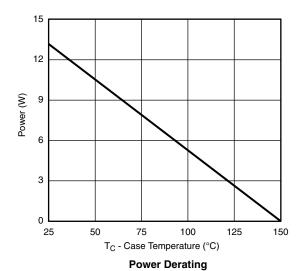






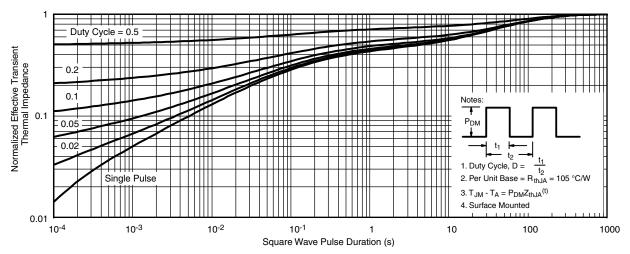
## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



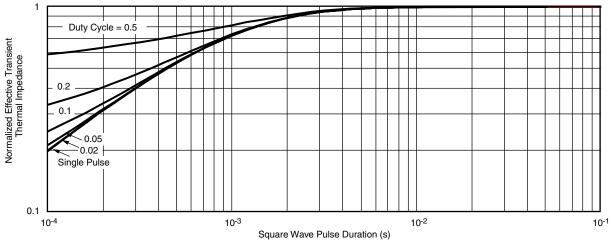


 $<sup>^*</sup>$  The power dissipation  $P_D$  is based on  $T_{J(max)}$  = 150  $^{\circ}$ C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package

## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient

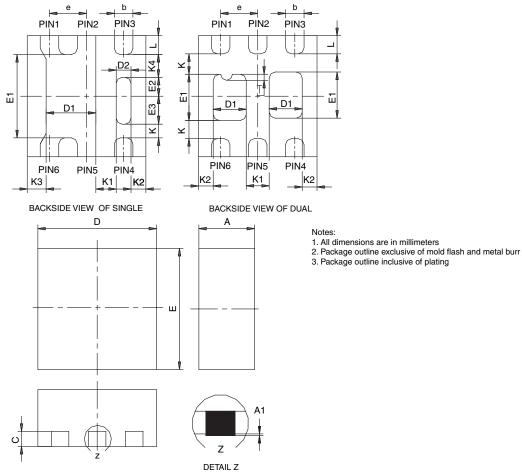


Normalized Thermal Transient Impedance, Junction-to-Case

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## PowerPAK® SC75-6L



			SINGL	E PAD			DUAL PAD					
DIM	MILLIMETERS			INCHES			MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max
Α	0.675	0.75	0.80	0.027	0.030	0.032	0.675	0.75	0.80	0.027	0.030	0.032
A1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002
b	0.18	0.25	0.33	0.007	0.010	0.013	0.18	0.25	0.33	0.007	0.010	0.013
С	0.15	0.20	0.25	0.006	0.008	0.010	0.15	0.20	0.25	0.006	0.008	0.010
D	1.53	1.60	1.70	0.060	0.063	0.067	1.53	1.60	1.70	0.060	0.063	0.067
D1	0.57	0.67	0.77	0.022	0.026	0.030	0.34	0.44	0.54	0.013	0.017	0.021
D2	0.10	0.20	0.30	0.004	0.008	0.012						
Е	1.53	1.60	1.70	0.060	0.063	0.067	1.53	1.60	1.70	0.060	0.063	0.067
E1	1.00	1.10	1.20	0.039	0.043	0.047	0.51	0.61	0.71	0.020	0.024	0.028
E2	0.20	0.25	0.30	0.008	0.010	0.012						
E3	0.32	0.37	0.42	0.013	0.015	0.017						
е	0.50 BSC		•		0.020 BSC	;	0.50 BSC				0.020 BSC	
K	0.180 TYP				0.007 TYP		0.245 TYP			0.010 TYP		
K1	0.275 TYP				0.011 TYP	)	0.320 TYP			0.013 TYP		
K2	0.200 TYP				0.008 TYP	)	0.200 BSC			0.008 TYP		
К3	0.255 TYP			0.010 TYP								
K4	0.300 TYP			0.012 TYP								
L	0.15	0.25	0.35	0.006	0.010	0.014	0.15	0.25	0.35	0.006	0.010	0.014
Т							0.03	0.08	0.13	0.001	0.003	0.005
	07404 Da	0. 00 A	- 07				0.03	0.08	0.13	0.001	0.003	L

ECN: C-07431 - Rev. C, 06-Aug-07

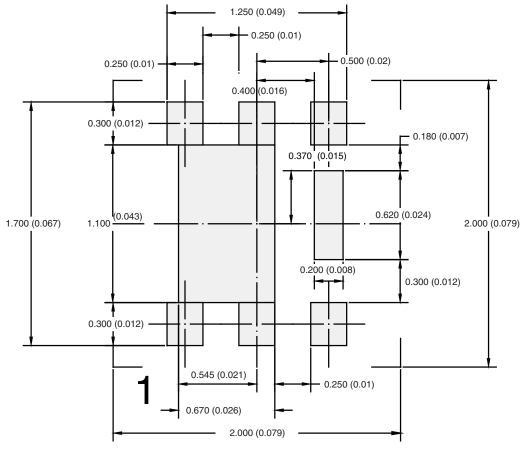
DWG: 5935

Document Number: 73000 06-Aug-07

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## RECOMMENDED PAD LAYOUT FOR PowerPAK® SC75-6L Single



Dimensions in mm/(Inches)

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ATTLICATION NO



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